

# European Network on New Sensing Technologies for Air Pollution Control and Environmental Sustainability - *EuNetAir*

COST Action TD1105

## WGs and MC Meeting at LINKÖPING, 3 - 5 June 2015

Action Start date: 01/07/2012 - Action End date: 30/06/2016

Year 3: 1 July 2014 - 30 June 2015 (*Ongoing Action*)

## Pulsed Laser Deposition of Metal Oxide Nanoparticles, Agglomerates, and Nanotrees

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WG1: Sensor Materials and Nanotechnology (Vice-Chair)

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OULUN YLIOPISTO

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EUROPEAN COOPERATION IN SCIENCE AND TECHNOLOGY





# Scientific context and objectives in the Action:

- **Background / Problem statement:**
  - Development of new sensitive and selective gas sensor materials for environmental quality control, public safety issues, medical, automotive applications such as Selective Catalytic Reaction (SCR), air conditioning system setups in aircrafts, spacecrafts, vehicles, houses, etc.
- **Brief reminder of MoU objectives:**
  - Study the sensitivity of nanostructured MO films to harmful gases, *e.g.*  $\text{NO}_x$ ,  $\text{NO}_2$ ,  $\text{H}_2$ ,  $\text{NH}_3$ , and VOC's
  - Utilizing grain size, phase transition, mixed phase, and *p-n* junction effects
  - Fabrication of sensors on various substrates including flexible substrates PET/PEN using printing techniques

# Pulsed Laser Deposition of Metal Oxide Nanoparticles, Agglomerates, and Nanotrees

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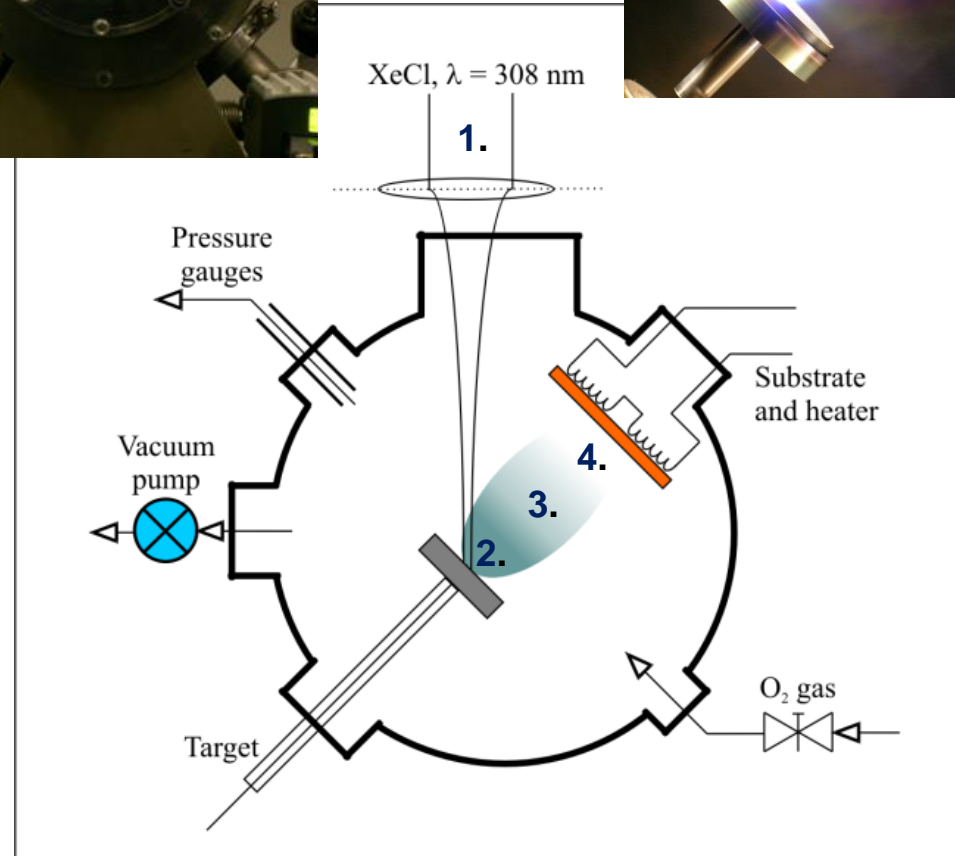
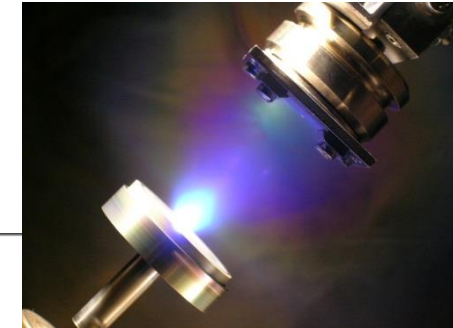
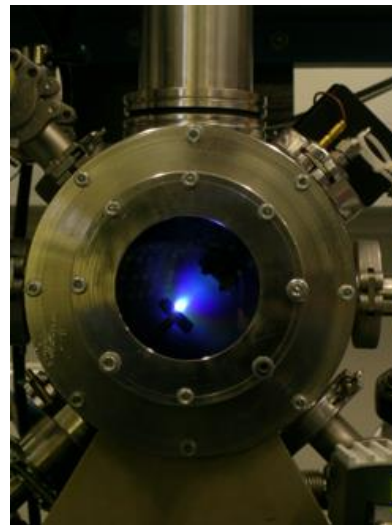
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University of Oulu, Finland

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Measurement technology,  
Saarland University, Germany

# Introduction:

## 1. Pulsed Laser Deposition (PLD):

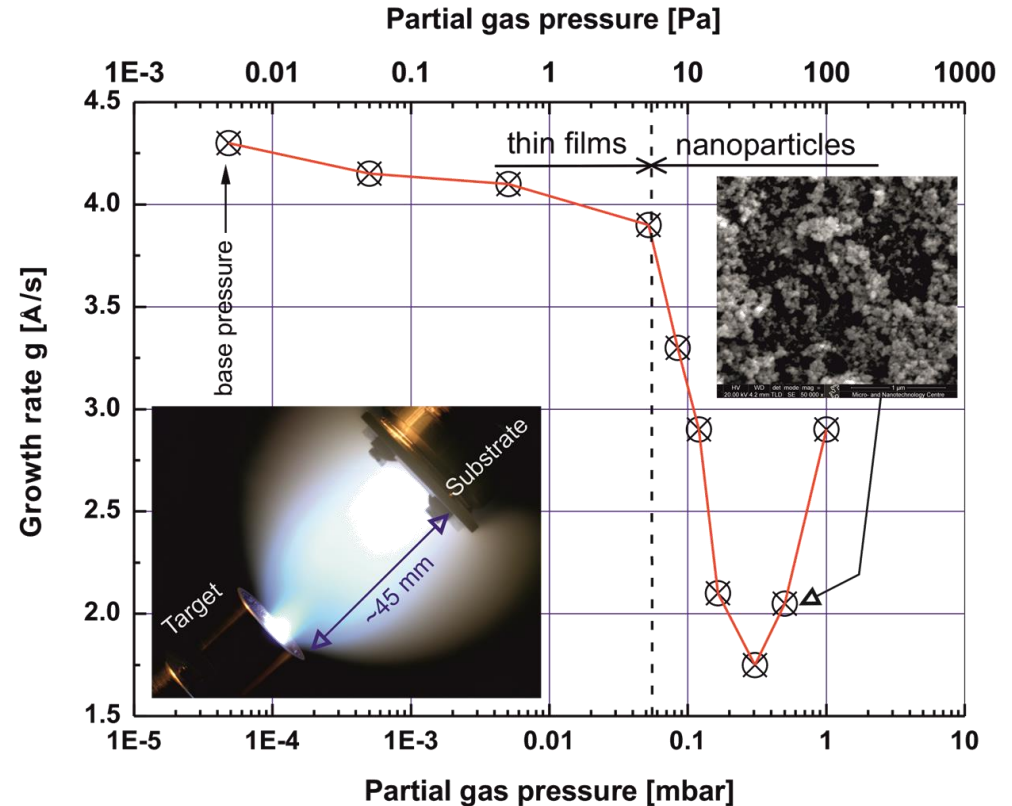
1. Focused laser pulse hits the target material surface placed in low-pressure conditions.
2. Plasma is generated by ablation and/or evaporation processes.
3. Pressure gradient inside the plasma is very high, and thus the plasma expands extremely fast in the direction perpendicular to target surface.
4. Atomic (and other) species of the plasma are collected on substrate surface to form a thin film.



# Introduction:

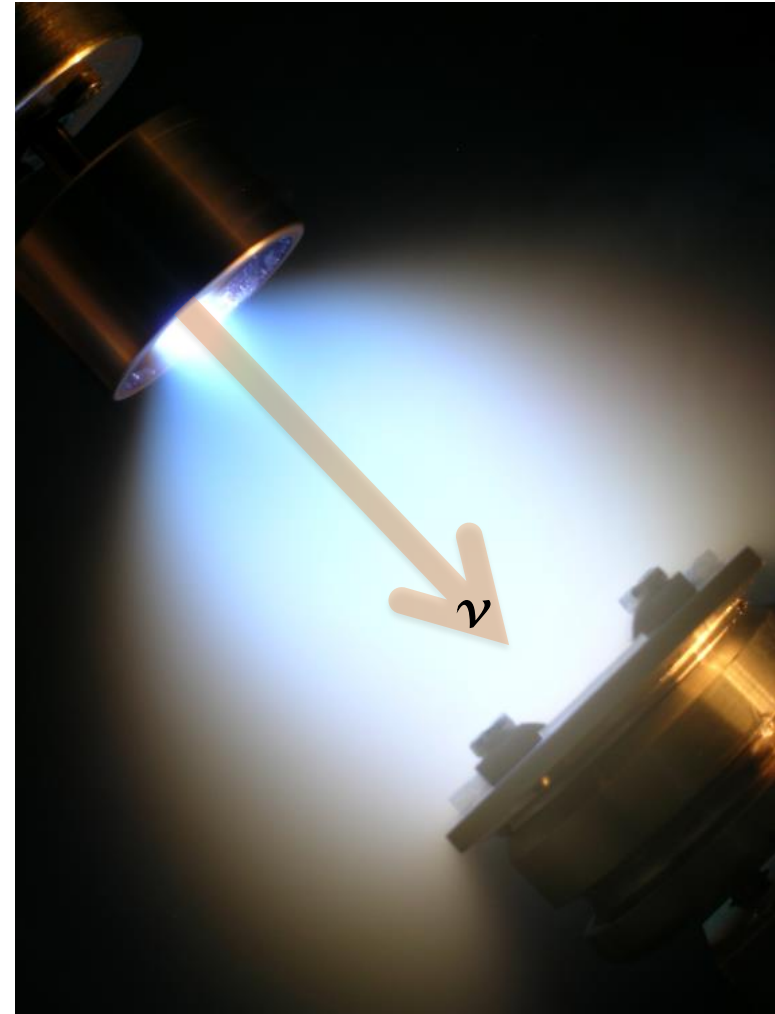
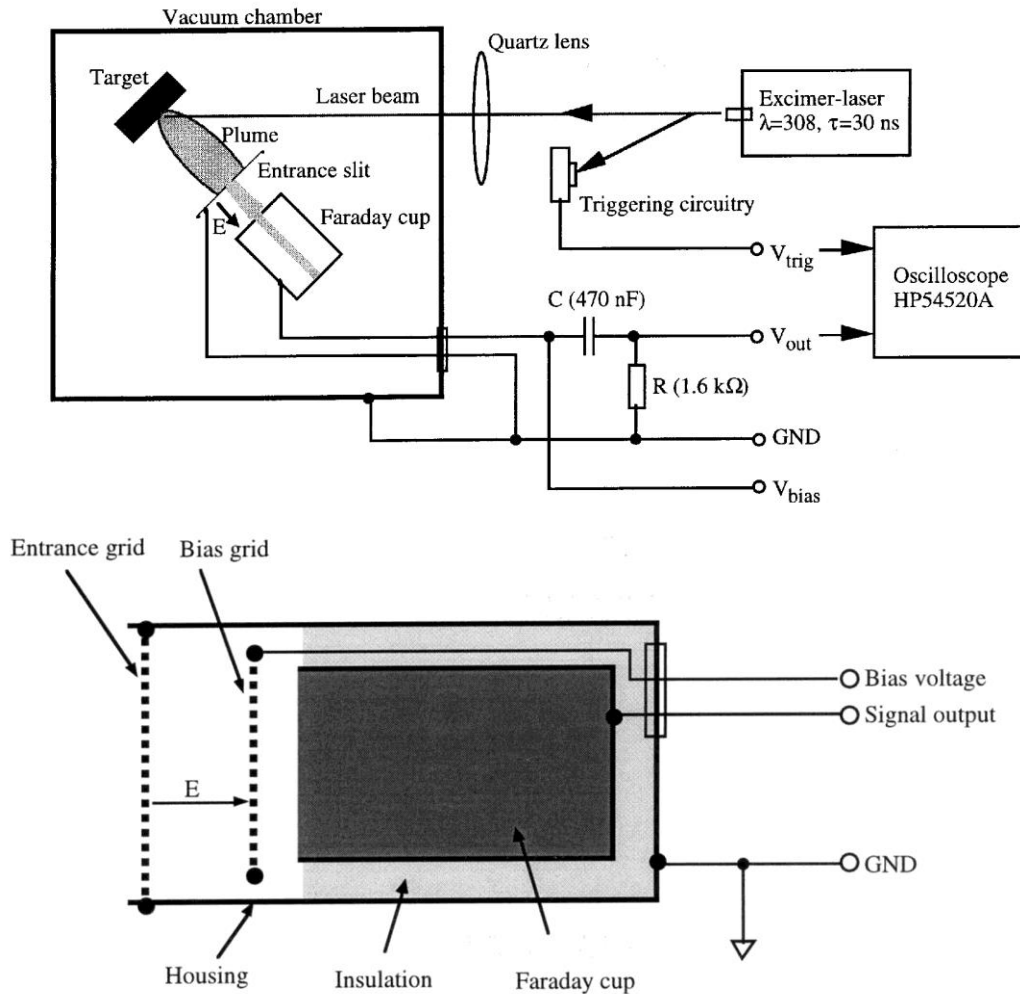
## 2. Particle Generation in PLD:

- Two points of generation: (i) target surface, and (ii) high density plasma.
- Reactions in plasma can lead into: (i) dissociation of particulates, or in (ii) nucleation of nanoparticles.
- Plasma can be controlled by deposition atmosphere, *i.e.* partial oxygen pressure  $p(\text{O}_2)$ , or by laser beam fluence ( $\text{J}/\text{cm}^2$ )
- Plasma can be controlled by deposition atmosphere, for example, by liquids – LAPLD.
- Extremely small particles,  $\phi < 5 \text{ nm}$ , can be grown.



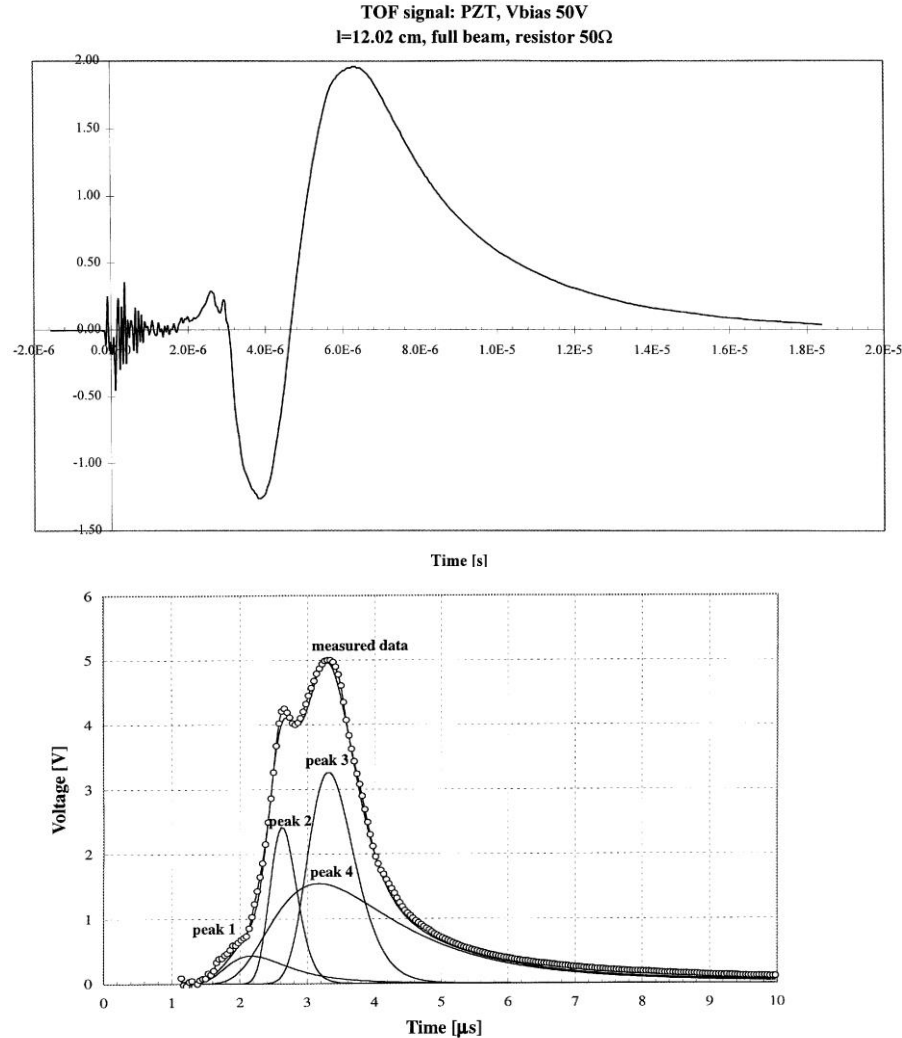
# Introduction:

## Time of Flight (TOF) measurements with Faraday cup:



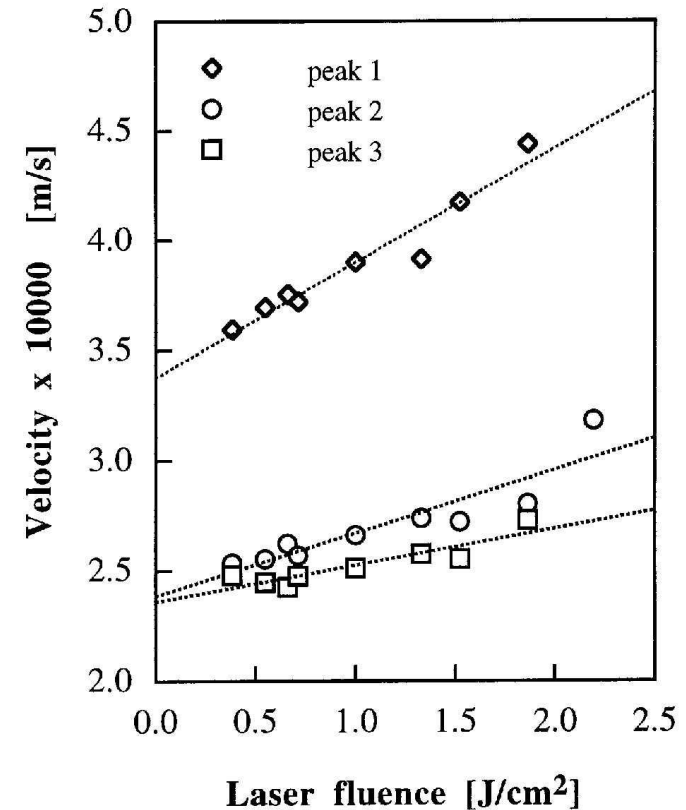
# Introduction:

## Time of Flight (TOF) measurements with Faraday cup:



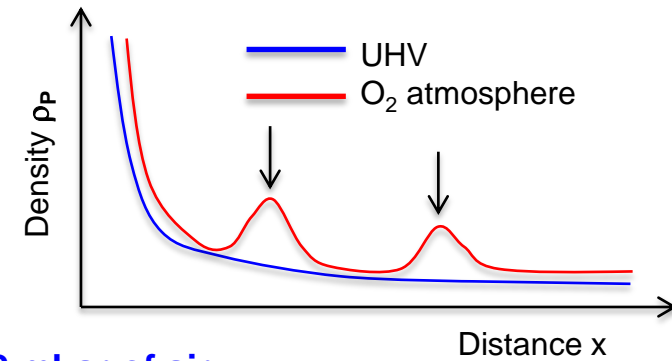
## Maxwell – Boltzman distribution:

$$f(v) = 4\pi \left( \frac{m}{2\pi kT} \right)^{3/2} v^2 \exp \left[ \frac{-mv^2}{2kT} \right]$$

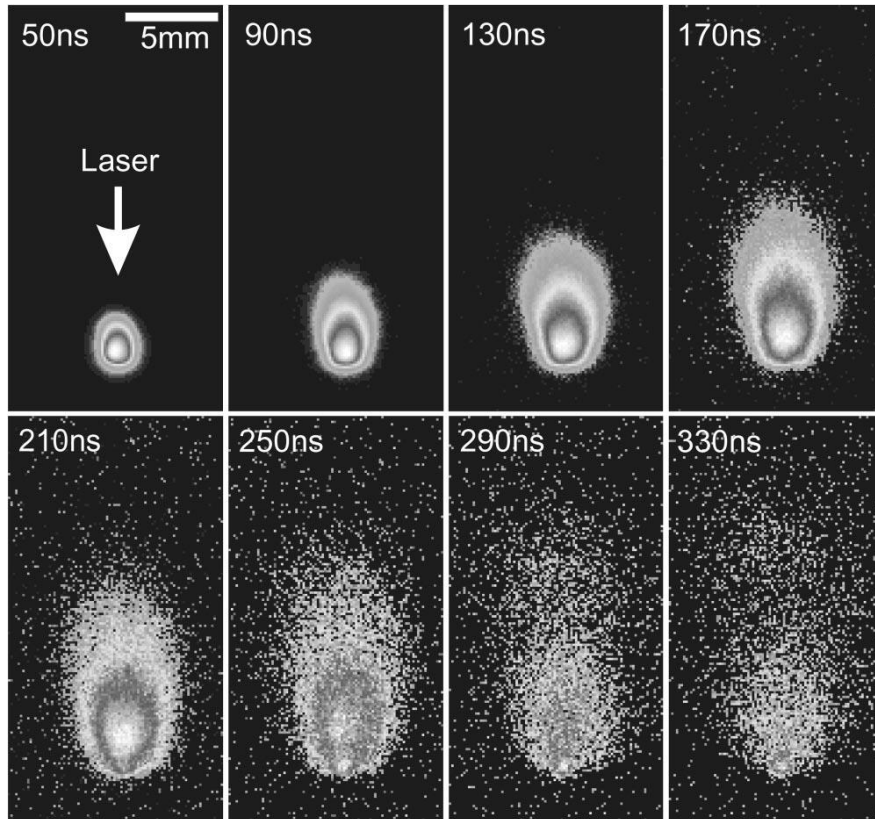


# Introduction:

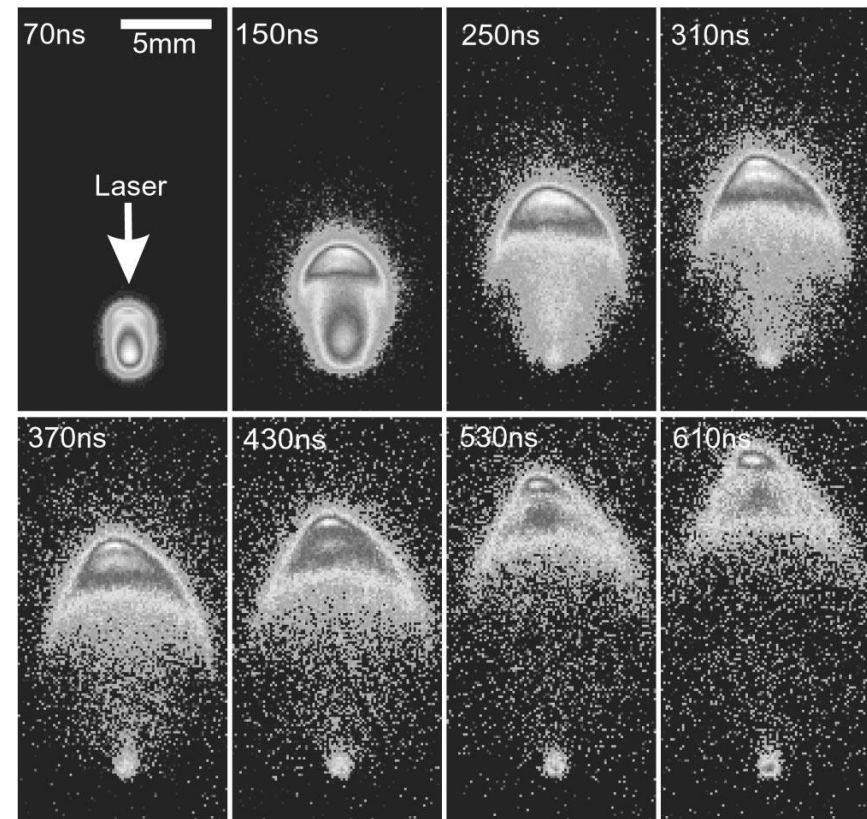
Fast ICCD camera images of expanding laser ablation plume of aluminum  
[S.S. Harilal *et al.*, Journal of Applied Physics 93(2003)2380]  
Effects of shock waves!



(a) in  $1 \times 10^{-6}$  mbar of air



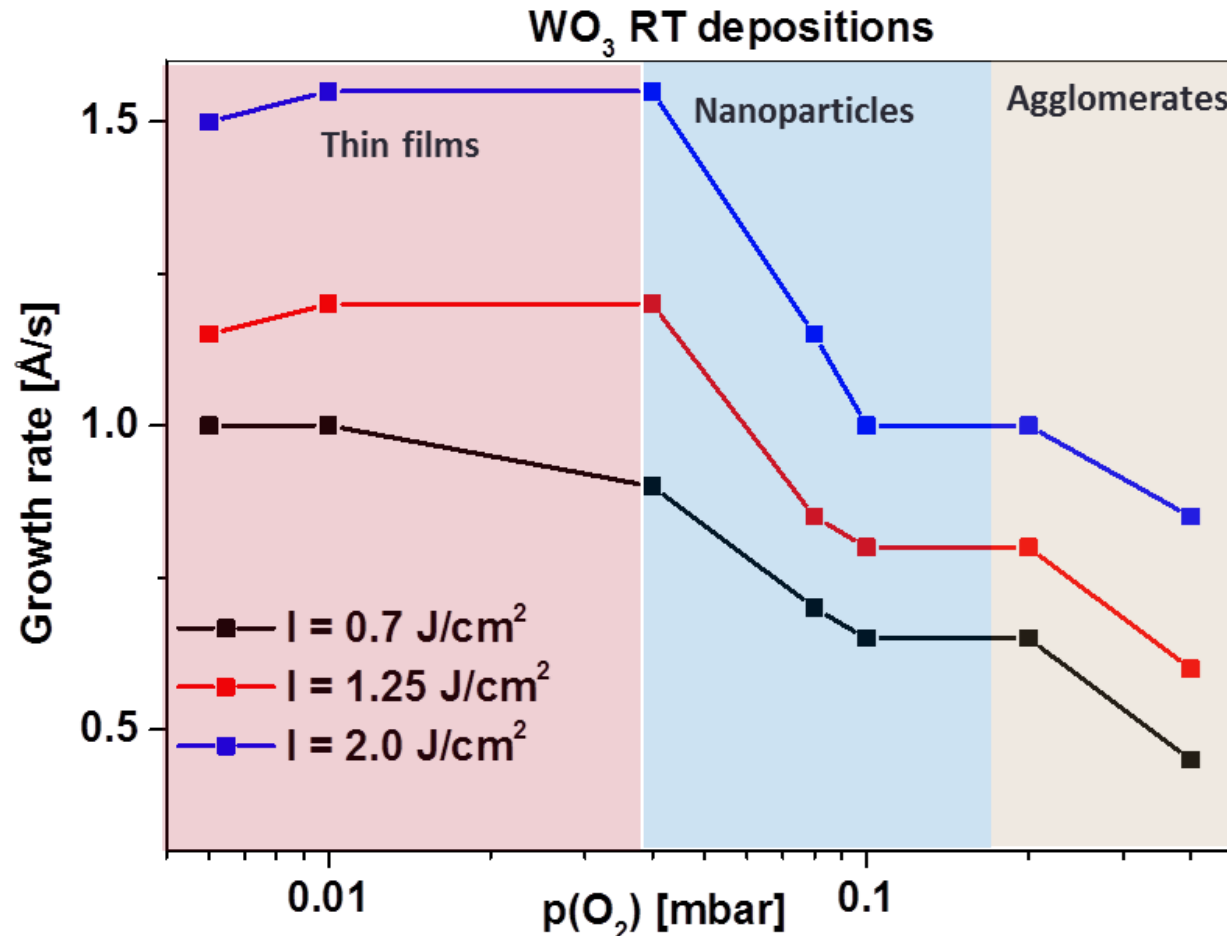
(b) in 0.2 mbar of air





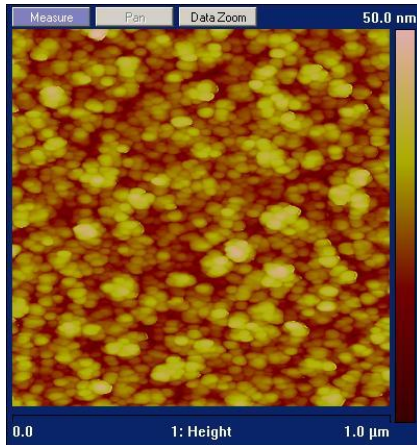
# Manufacturing of WO<sub>3</sub> nanostructures

- Ceramic target of pure WO<sub>3</sub> was used in PLD process
- In QCM measurements, change in the growth modes from thin films to nanoparticle agglomerates was seen

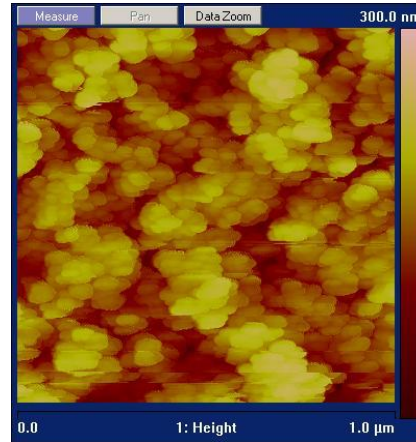


# Manufacturing of $\text{WO}_3$ nanostructures

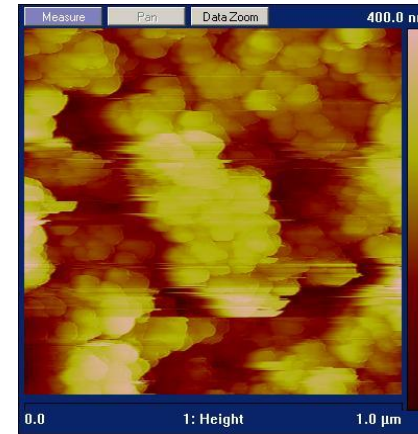
$p(\text{O}_2) = 0.08$  mbar



$p(\text{O}_2) = 0.2$  mbar

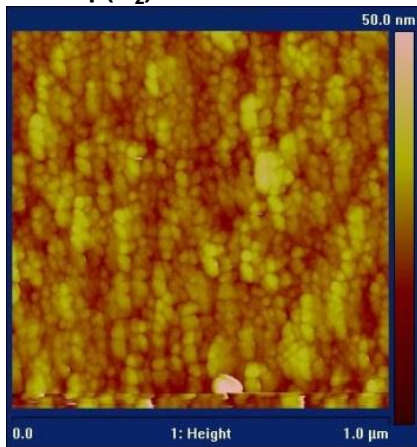


$p(\text{O}_2) = 0.5$  mbar

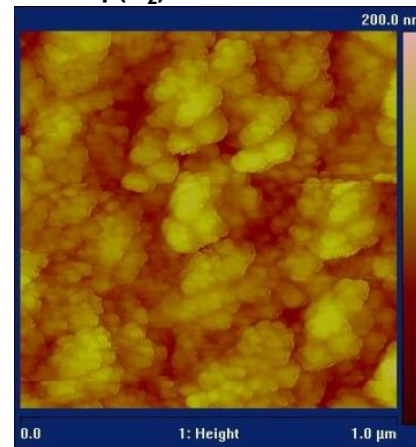


Effects of post-annealing at 400 °C for 1 h period:

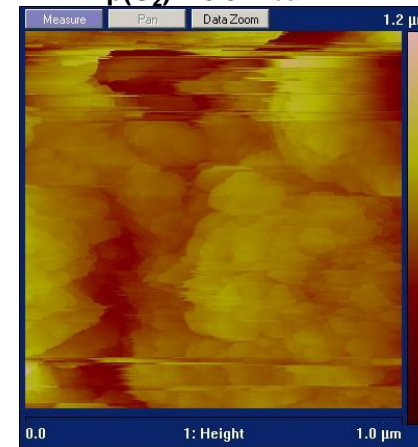
$p(\text{O}_2) = 0.08$  mbar



$p(\text{O}_2) = 0.2$  mbar



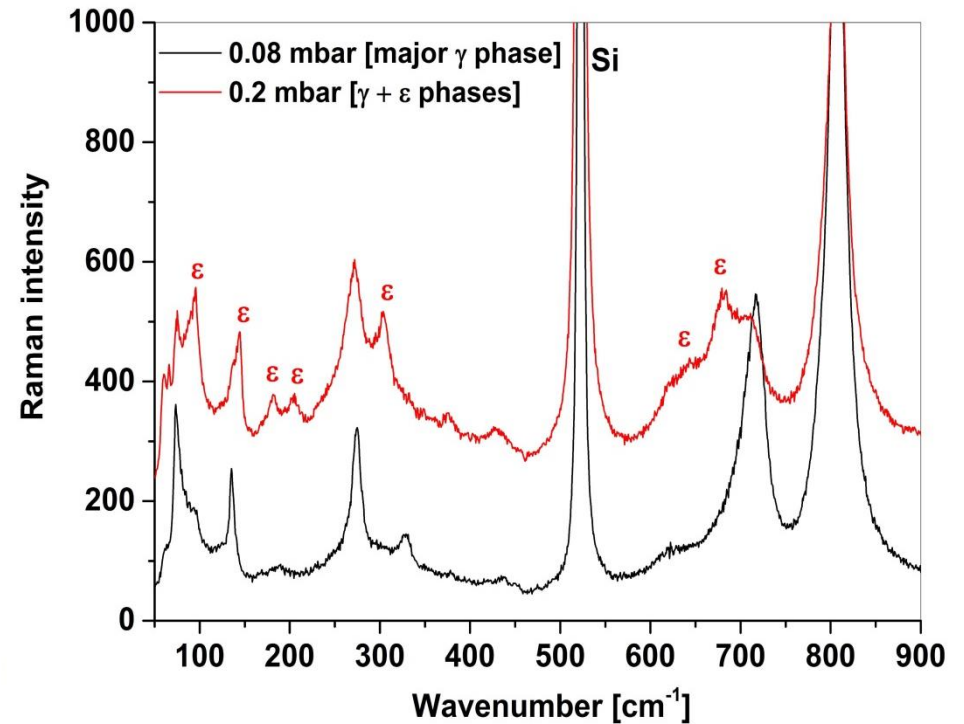
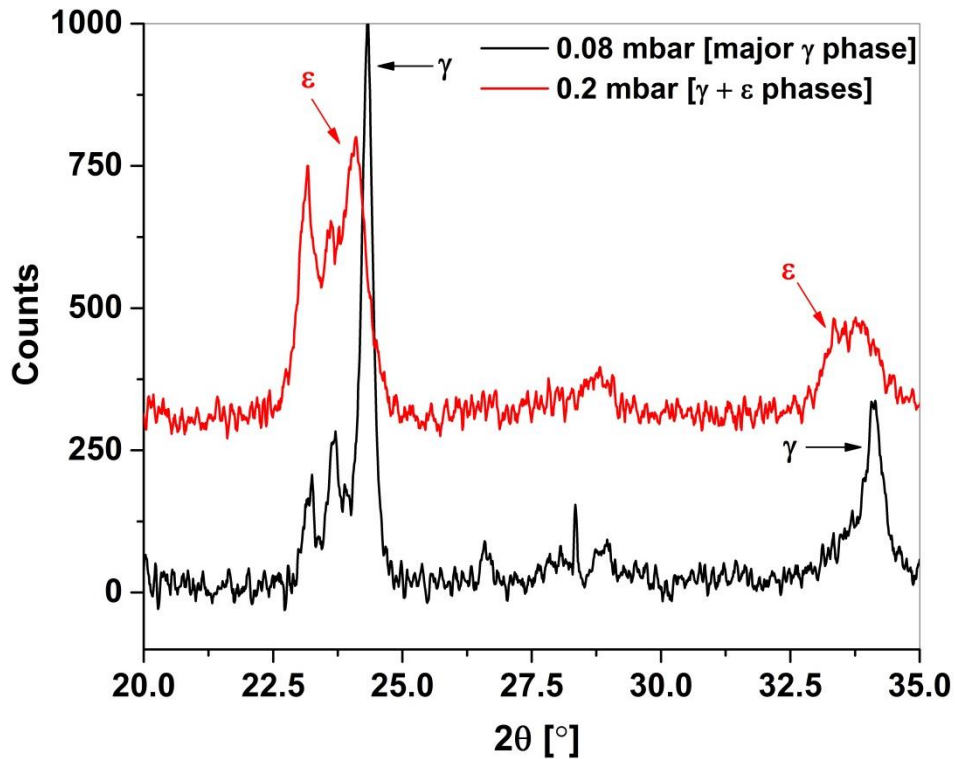
$p(\text{O}_2) = 0.5$  mbar



# Manufacturing of $\text{WO}_3$ nanostructures

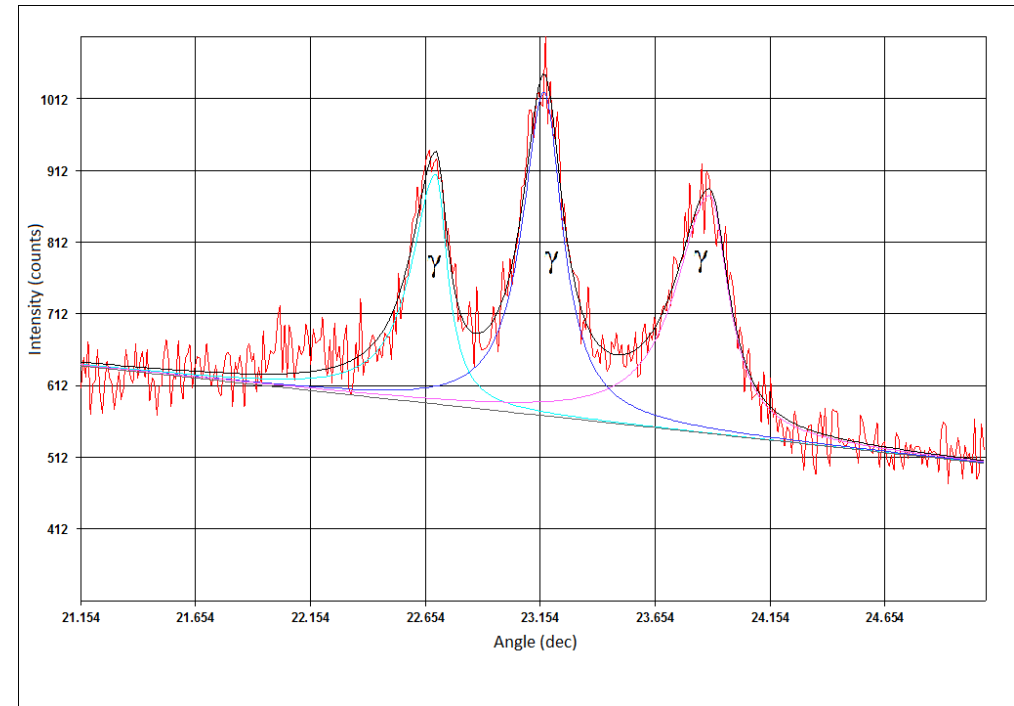
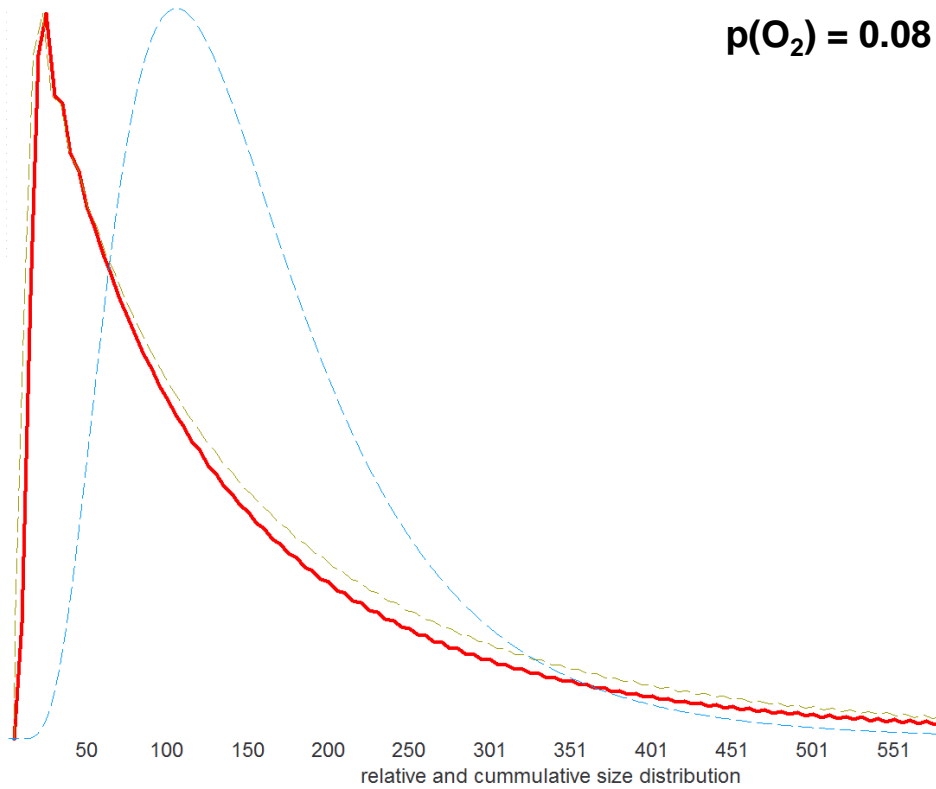
XRD and Raman Spectroscopy: layers are composed of  $\gamma$ -phase and  $\epsilon$ -phase of  $\text{WO}_3$  :

$T_{\text{ann}} = 400 \text{ }^\circ\text{C}$ :



# Manufacturing of $\text{WO}_3$ nanostructures

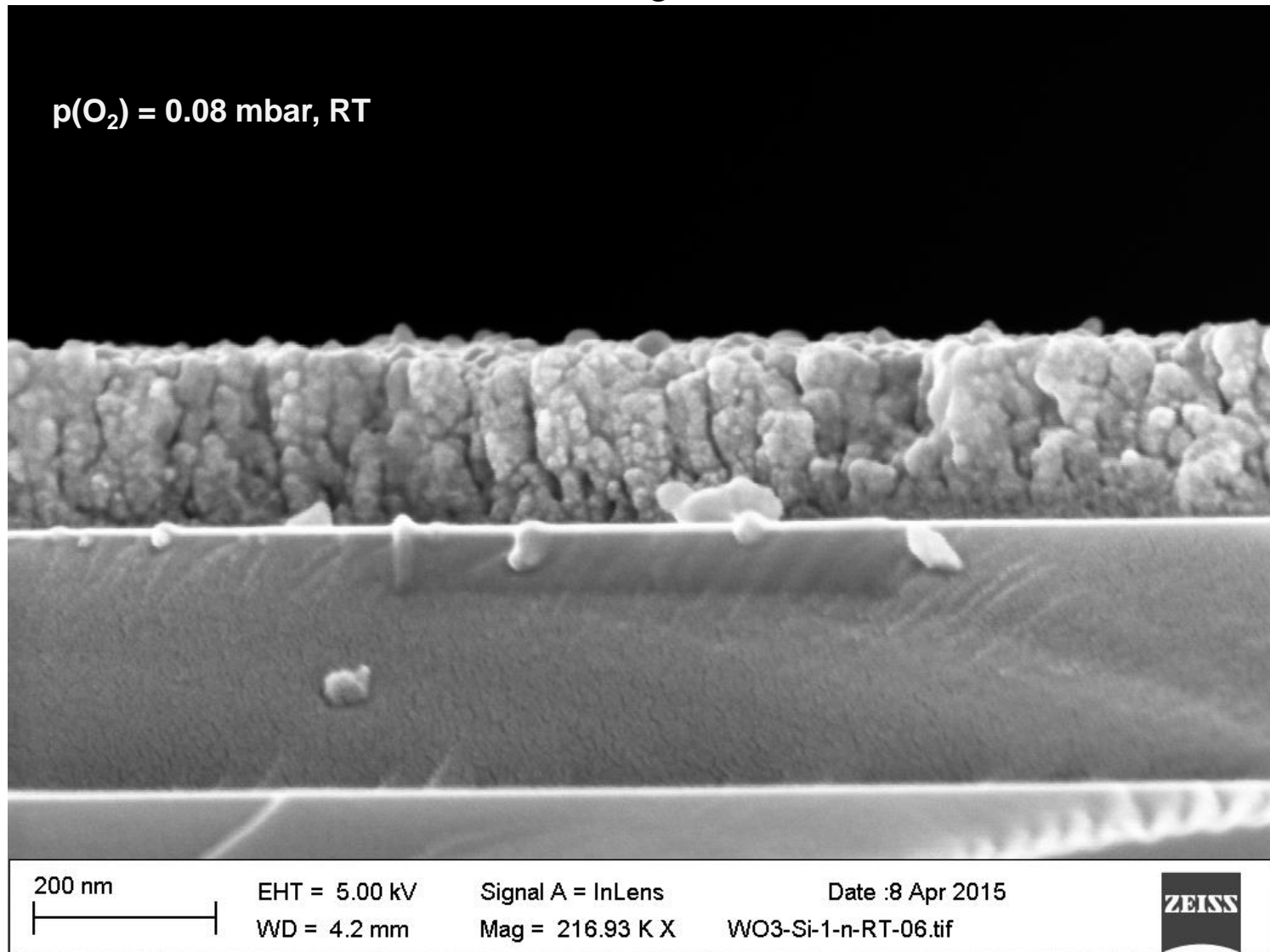
$p(\text{O}_2) = 0.08 \text{ mbar}$ ,  $T_{\text{ann}} = 500 \text{ }^\circ\text{C}$ :



Warren-Averbach,  $\langle D \rangle$  from distr.: 143 Å (may be too low due to truncation)

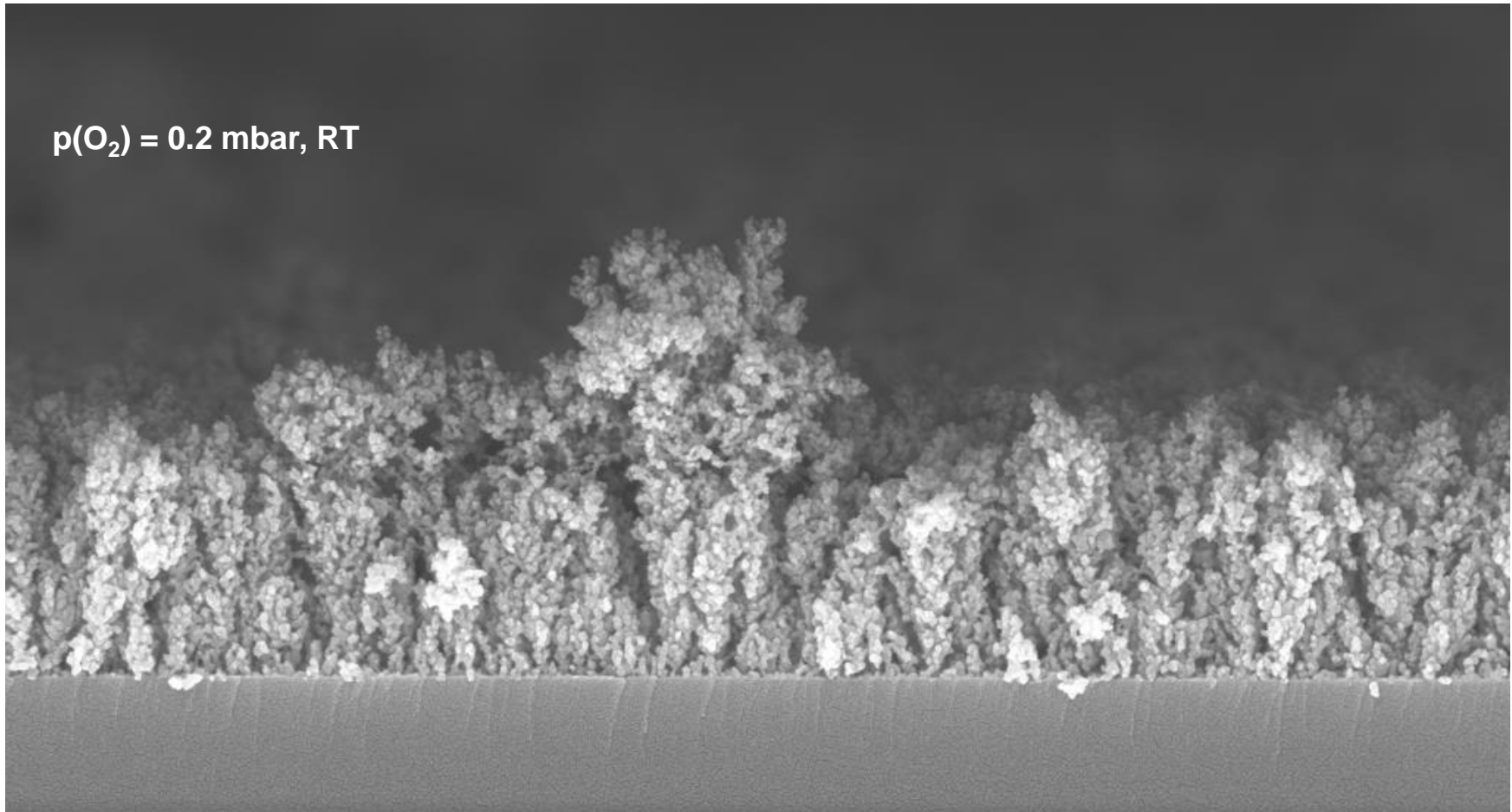
Warren-Averbach,  $\langle D \rangle$  from slope: 176 Å

# Manufacturing of $\text{WO}_3$ nanostructures

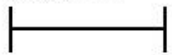


# Manufacturing of $\text{WO}_3$ nanostructures

$p(\text{O}_2) = 0.2 \text{ mbar, RT}$



300 nm



EHT = 5.00 kV

WD = 4.4 mm

Signal A = InLens

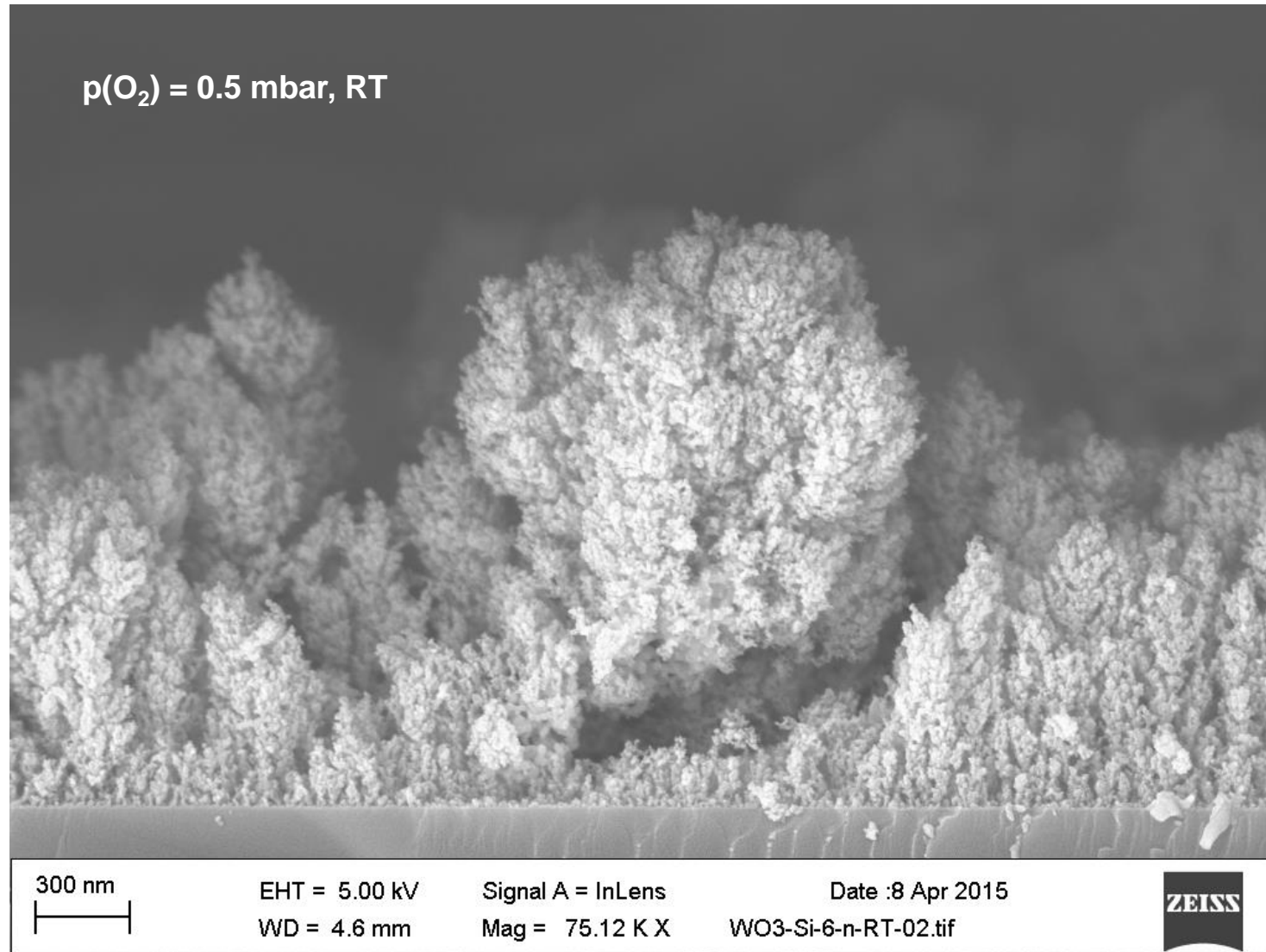
Mag = 89.64 K X

Date :8 Apr 2015

WO3-Si-2-n-RT-08.tif

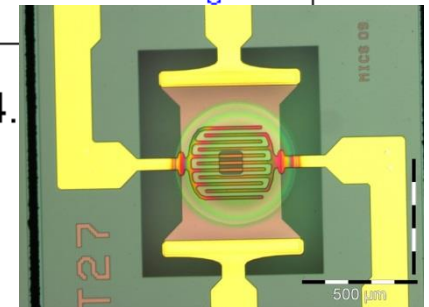
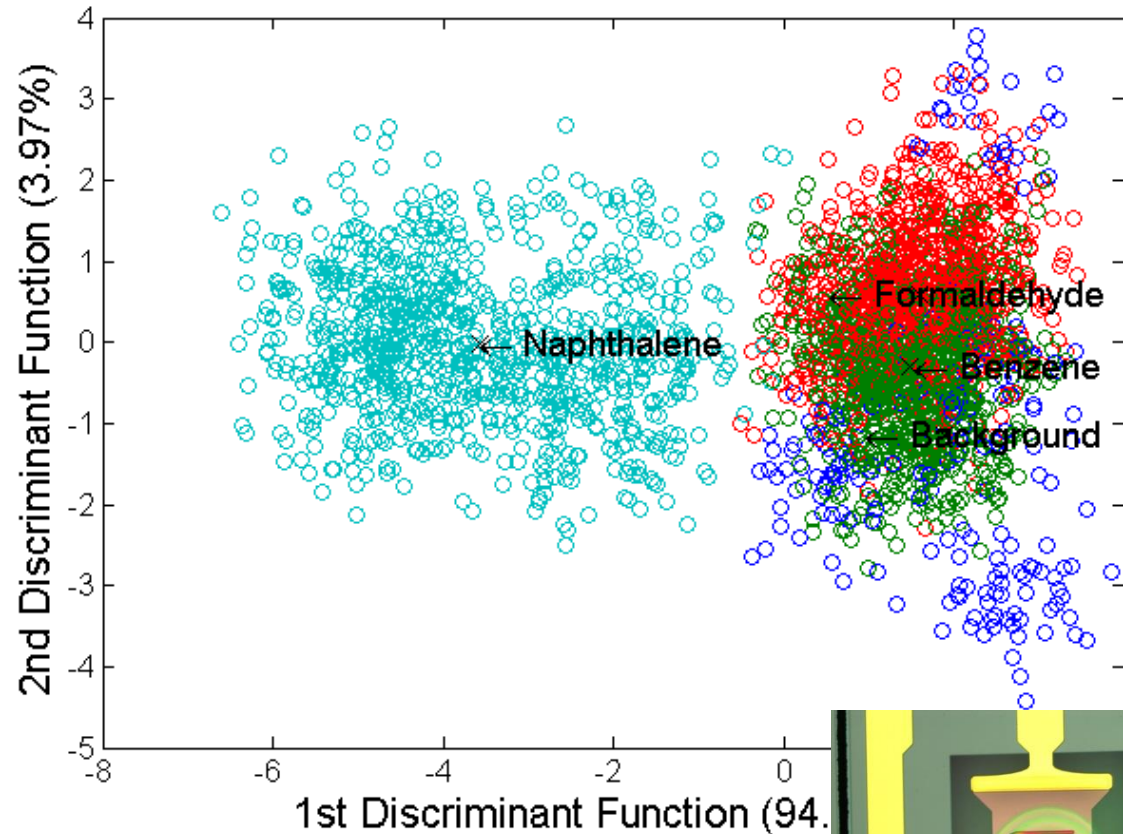
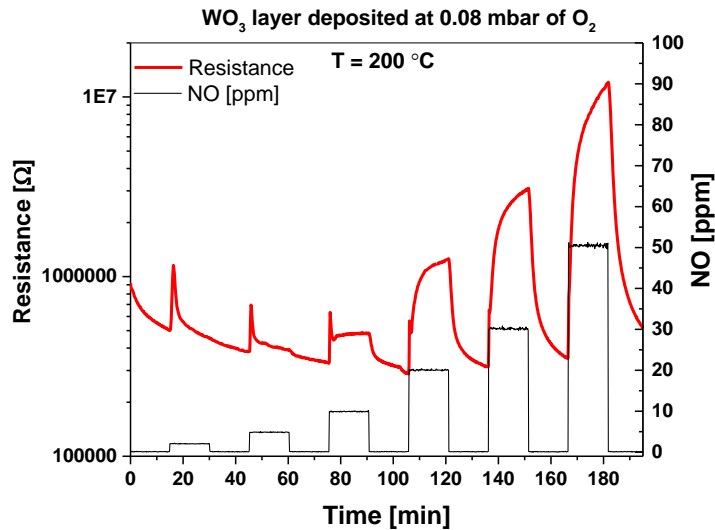


# Manufacturing of $\text{WO}_3$ nanostructures



# Manufacturing of $WO_3$ nanostructures

$p(O_2) = 0.2$  mbar,  $T_{ann} = 400$  °C:  
Linear Discriminant Analysis  
(LDA) at naphthalene  
concentrations below  
5 ppb-level.

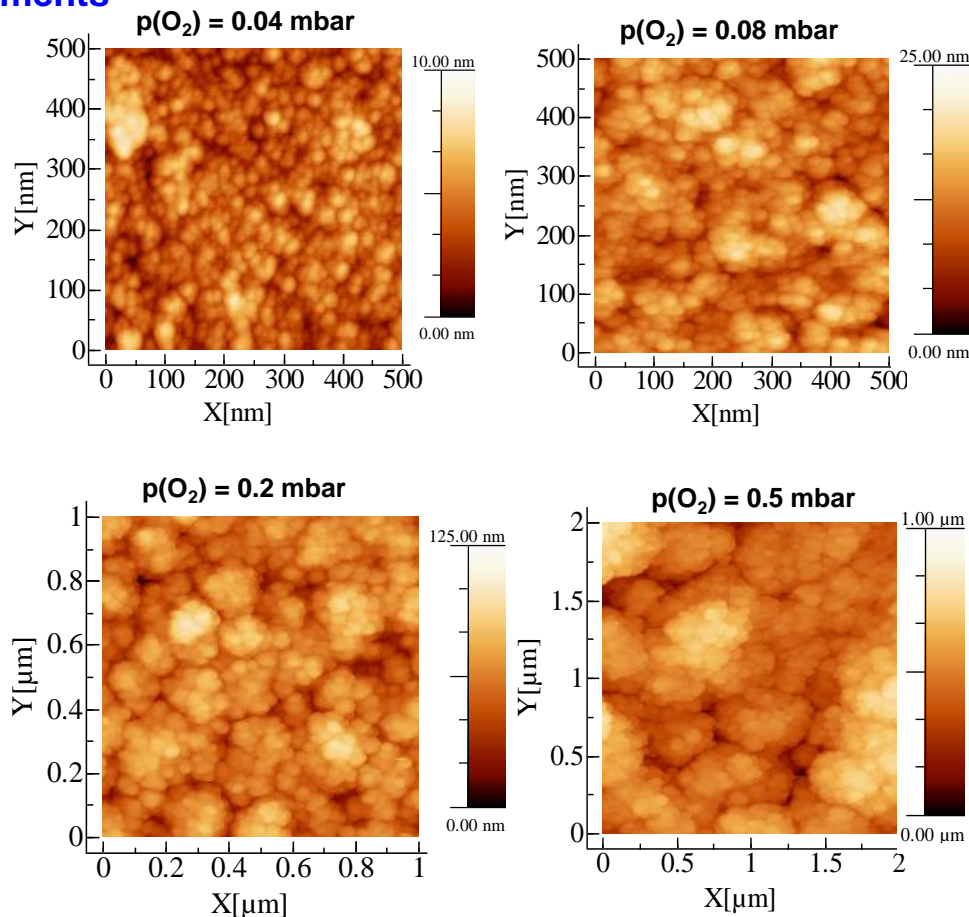
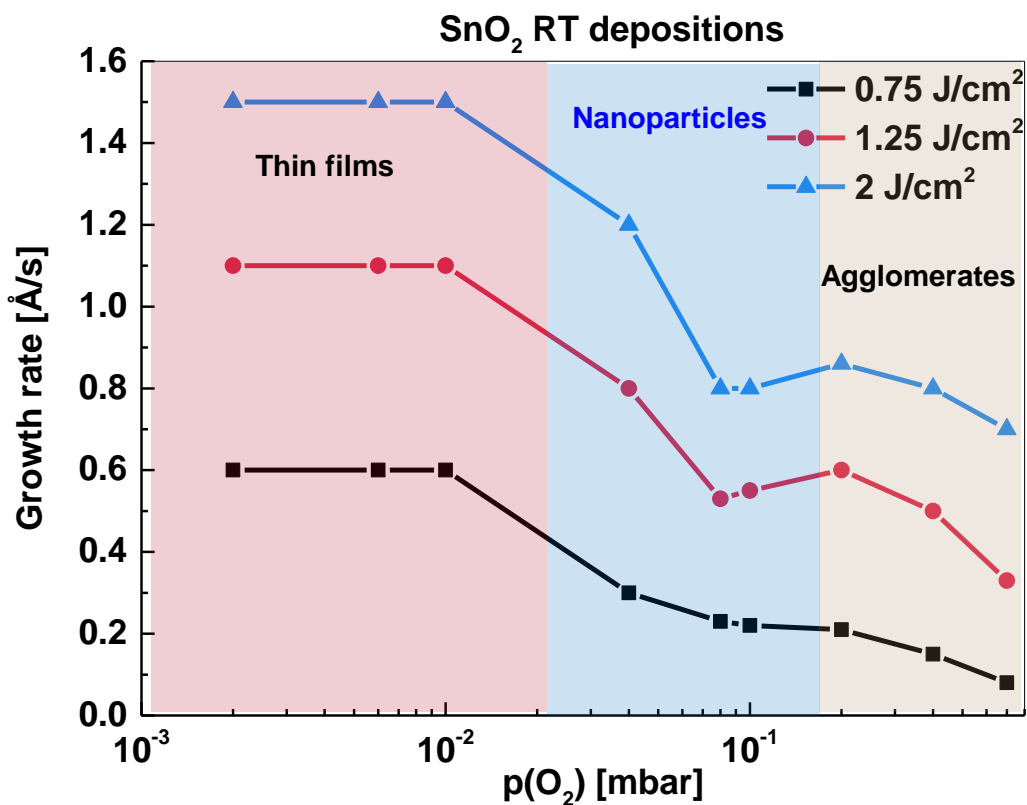


**WO<sub>3</sub> gas sensing properties: the WO<sub>3</sub> layers are extremely selective to ppb-levels of naphthalene!**

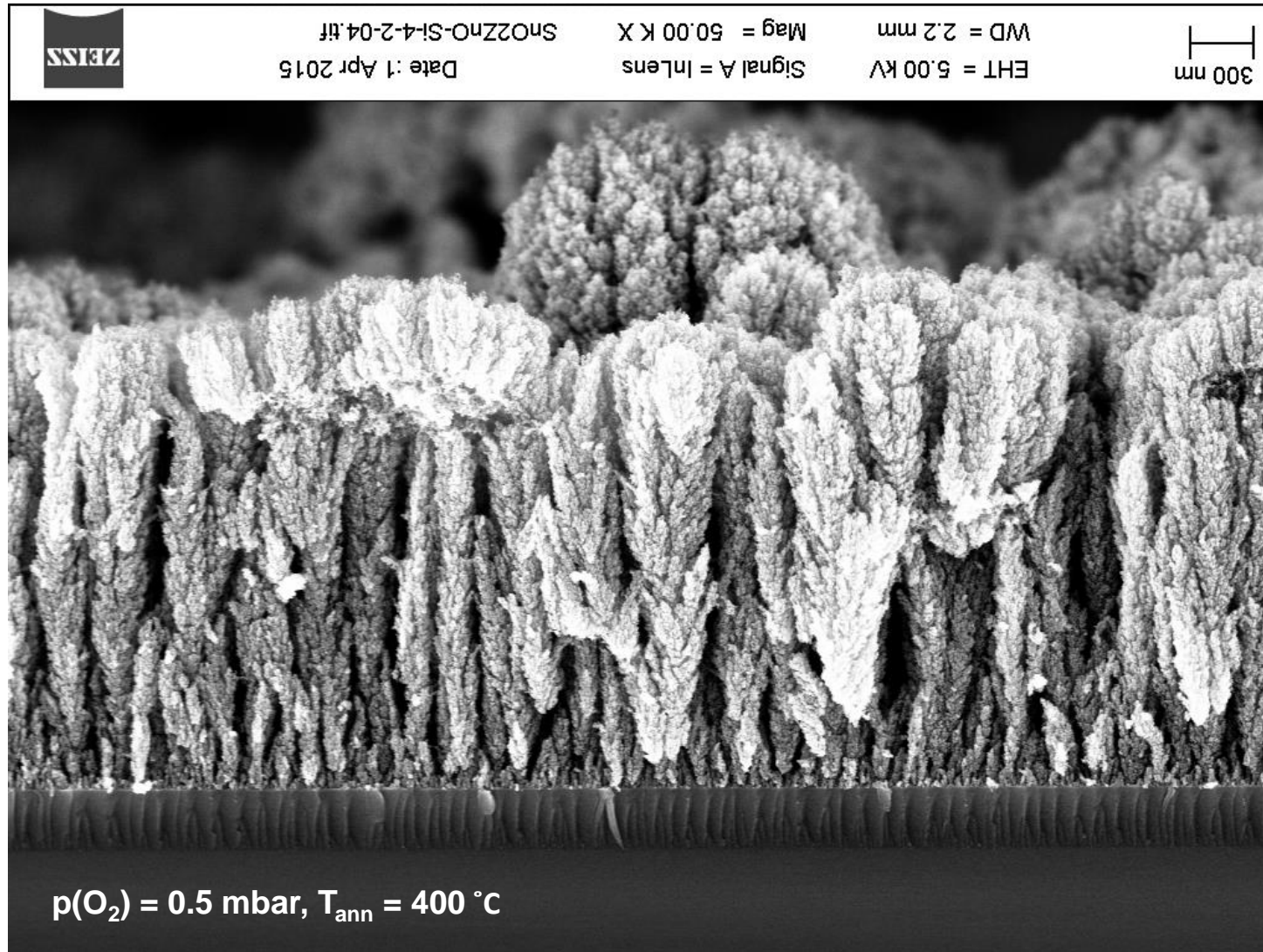


# Manufacturing of SnO<sub>2</sub> nanostructures

- Ceramic target of 99.7% of SnO<sub>2</sub> + 0.3% of ZnO as sintering aid was used in PLD process
- In QCM measurements, change in the growth modes from thin films to nanoparticle agglomerates was seen
- The QCM result was confirmed by AFM measurements



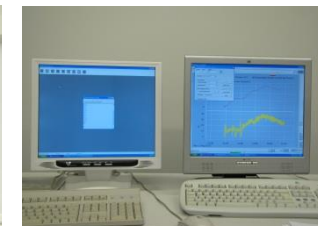
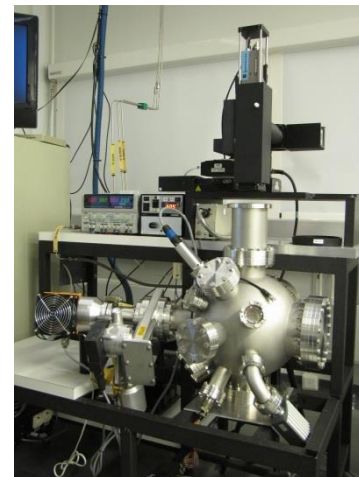
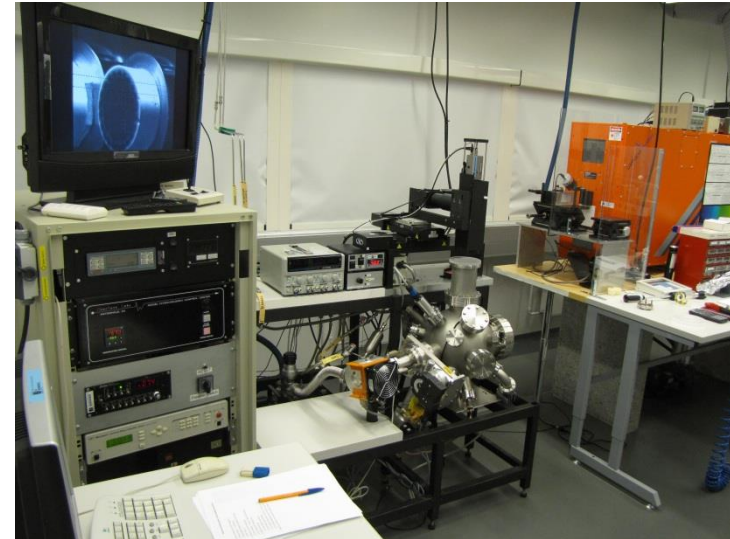
# Manufacturing of SnO<sub>2</sub> nanostructures



## Research Facilities available for the Partner:

### **PLD laboratory in UO-FETF:**

- XeCl-excimer laser (LamdaPhysik 201)
- $\lambda = 308$  nm (248 nm optional)
- $\tau = 25$  ns,  $E_{\max} = 400$  mJ,  $f_{\max} = 10$  Hz
- Optics with continuous energy adjustment
- Computer controlled micromovement stage for laser beam guiding and scanning
- Custom modified PLD chamber (K.J. Lesker)
- UHV capability ( $\sim 10^{-7}$  mbar)
- Computer controlled rotating two-target system
- Sample holder  $\phi = 1$  inch,  $T_{\max} = 900$  °C
- Gas atmosphere control from  $\sim 0.0005$  mbar
- QCM rate/thickness monitor
- Fully computerized target motion,
- Gas atmosphere and profile, temperature profile, and laser controllers in order to perform automatized PLD procedures.





## Suggested **R&I Needs** for future research

- **Research directions as PRIORITIES:**
- Development of mixed-phase structures of MO's for gas sensing applications!
- Development of fabrication methods of  $WO_3$ ,  $V_2O_5$ ,  $SnO_2$ , etc. nanostructures in various morphologies and geometries!
- Detailed structural characterization and physics of gas sensing mechanism.
- Utilization of phase transitions and p-n junction effects in gas sensing processes!
- Integration into low-cost mass-production processes.